# The RF Line NPN Silicon RF Power Transistor

The TP3032 is designed for 26 volts, common emitter, 960 MHz base station amplifiers, for use in analog and digital systems.

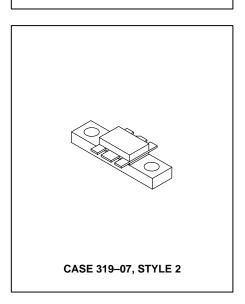
- Specified 26 Volts, 960 MHz Characteristics Output Power — 21 Watts Gain — 7.5 dB min
- Silicon Nitride Passivated
- Gold Metallized, Emitter Ballasted for Long Life and Resistance to Metal Migration
- · Class AB Operation
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

#### **MAXIMUM RATINGS**

Rating	Symbol Value		Unit
Collector–Emitter Voltage	VCER	40	Vdc
Collector-Base Voltage	Vсво	48	Vdc
Emitter-Base Voltage	VEBO	3.5	Vdc
Collector–Current — Continuous	IC	4	Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	52.5 0.3	Watts W/°C
Storage Temperature Range	T <sub>stg</sub>	- 65 to +150	°C
Operating Junction Temperature	TJ	200	°C

## **TP3032**

21 W, 960 MHz RF POWER TRANSISTOR NPN SILICON



#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (1)	$R_{\theta JC}$	3.3	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•				
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 30 mA, R <sub>BE</sub> = 75 Ω)	V(BR)CER	40	_	_	Vdc
Emitter–Base Breakdown Voltage (IE = 5 mAdc)	V(BR)EBO	3.5	_	_	Vdc
Collector–Base Breakdown Voltage (IC = 30 mAdc)	V(BR)CBO	48	_	_	Vdc
Collector–Emitter Leakage ( $V_{CE}$ = 26 V, $R_{BE}$ = 75 $\Omega$ )	ICER	_	_	8	mA
ON CHARACTERISTICS	•				
DC Current Gain (IC =1 Adc, VCE = 10 Vdc)	hFE	15	_	80	_

NOTE: (continued)

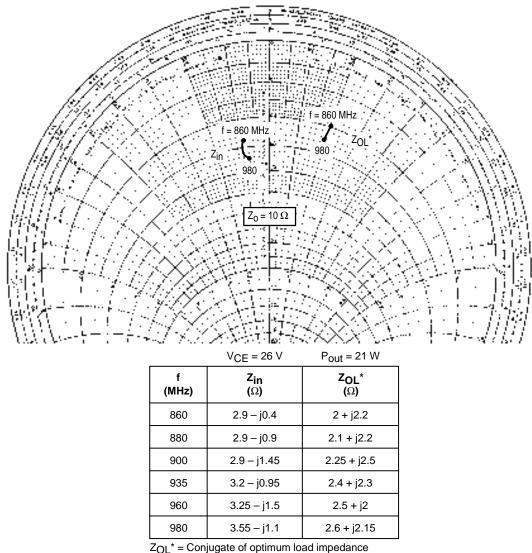
<sup>1.</sup> Thermal resistance is determined under specified RF operating condition.





### **ELECTRICAL CHARACTERISTICS** — **continued** ( $T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS		•			
Output Capacitance $(V_{CB} = 26 \text{ V}, I_E = 0, f = 1 \text{ MHz})$	C <sub>ob</sub>	_	30	_	pF
FUNCTIONAL TESTS					
Common–Emitter Amplifier Gain (VCC = 26 V, P <sub>out</sub> = 21 W, I <sub>CQ</sub> = 100 mA, f = 960 MHz)	Gp	7.5	8.5	_	dB
Load Mismatch (V <sub>CC</sub> = 26 V, P <sub>Out</sub> = 21 W, I <sub>CQ</sub> = 100 mA, Load VSWR = 5:1, at All Phase Angles at Frequency of Test)	Ψ	No Degradation in Output Power			
Collector Efficiency (V <sub>CC</sub> = 26 V, P <sub>out</sub> = 21 W, f = 960 MHz)	η	50	55	_	%
Over Drive (V <sub>CC</sub> = 26 V, P <sub>in</sub> = 6 W, f = 960 MHz)	OD	No Degradation in Output Power			



Z<sub>OL</sub>\* = Conjugate of optimum load impedance into which the device operates at a given output power, voltage, current and frequency.

Figure 1. Series Equivalent Input and Output Impedances

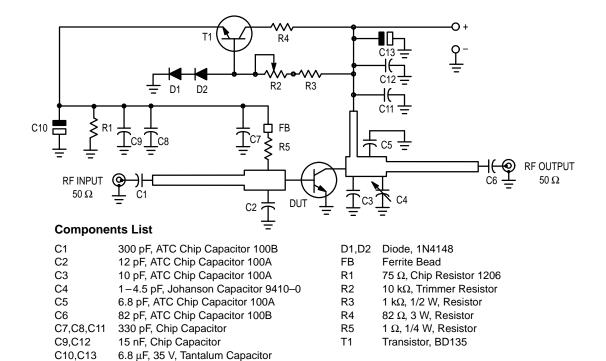


Figure 2. 960 MHz Test Circuit Schematic

#### **TYPICAL CHARACTERISTICS**

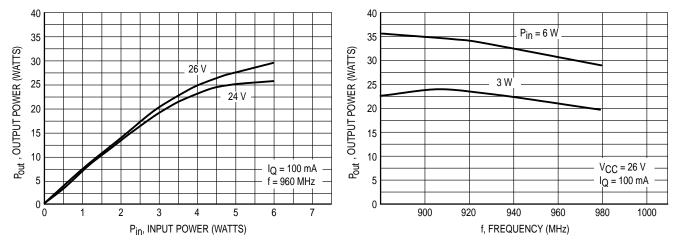


Figure 3. Output Power versus Input Power

Figure 4. Output Power versus Frequency

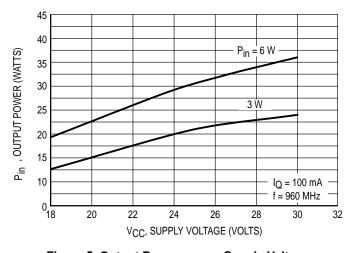
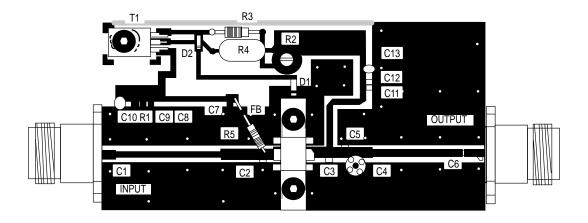


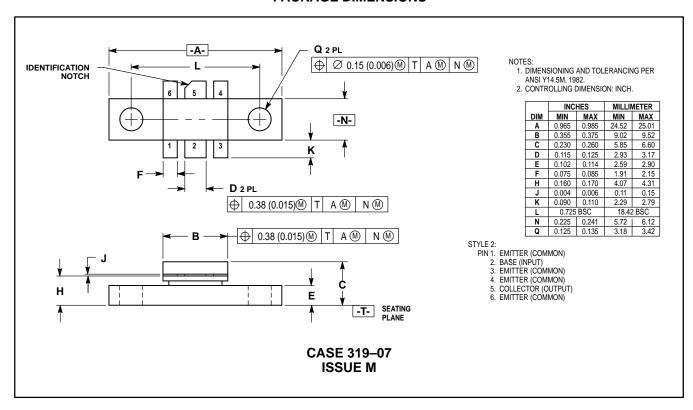
Figure 5. Output Power versus Supply Voltage

MOTOROLA RF DEVICE DATA TP3032



**Figure 6. Test Circuit Components View** 

#### **PACKAGE DIMENSIONS**



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